

OH017

GaAs hall element

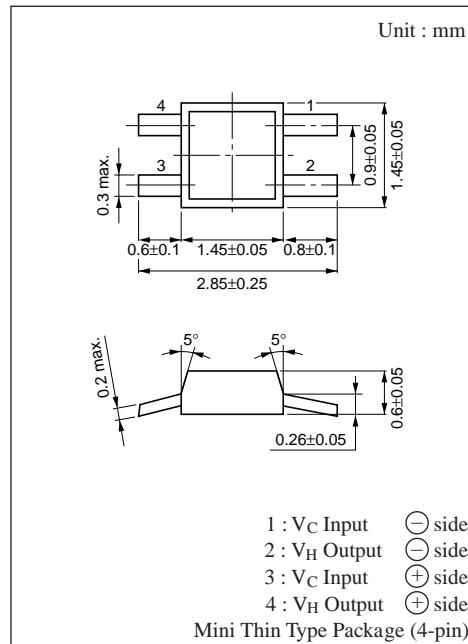
Magnetic sensor

■ Features

- Hall voltage : typ. 90mV($V_C = 3V$, $B = 0.1T$)
- Input resistance : typ. $2k\Omega$ (min. $1.5k\Omega$)
- Output resistance : typ. $7k\Omega$
- Low current dissipation type
- Mini thin type (4-pin) package. Automatic insertion through taping and magazine possible.

■ Applications

- Various hall motor
(Applicable to CD, VD, VCR, FDD, and other portable equipment)
- Applicable to wide-varying field (OA equipment, etc.)



Marking Symbol : D

■ Absolute Maximum Ratings ($T_a = 25^\circ C$)

Parameter	Symbol	Rating	Unit
Control voltage	V_C	6	V
Power dissipation	P_D	100	mW
Operating ambient temperature	T_{opr}	-10 to +125	°C
Storage temperature	T_{stg}	-55 to +125	°C

■ Electrical Characteristics ($T_a = 25^\circ C$)

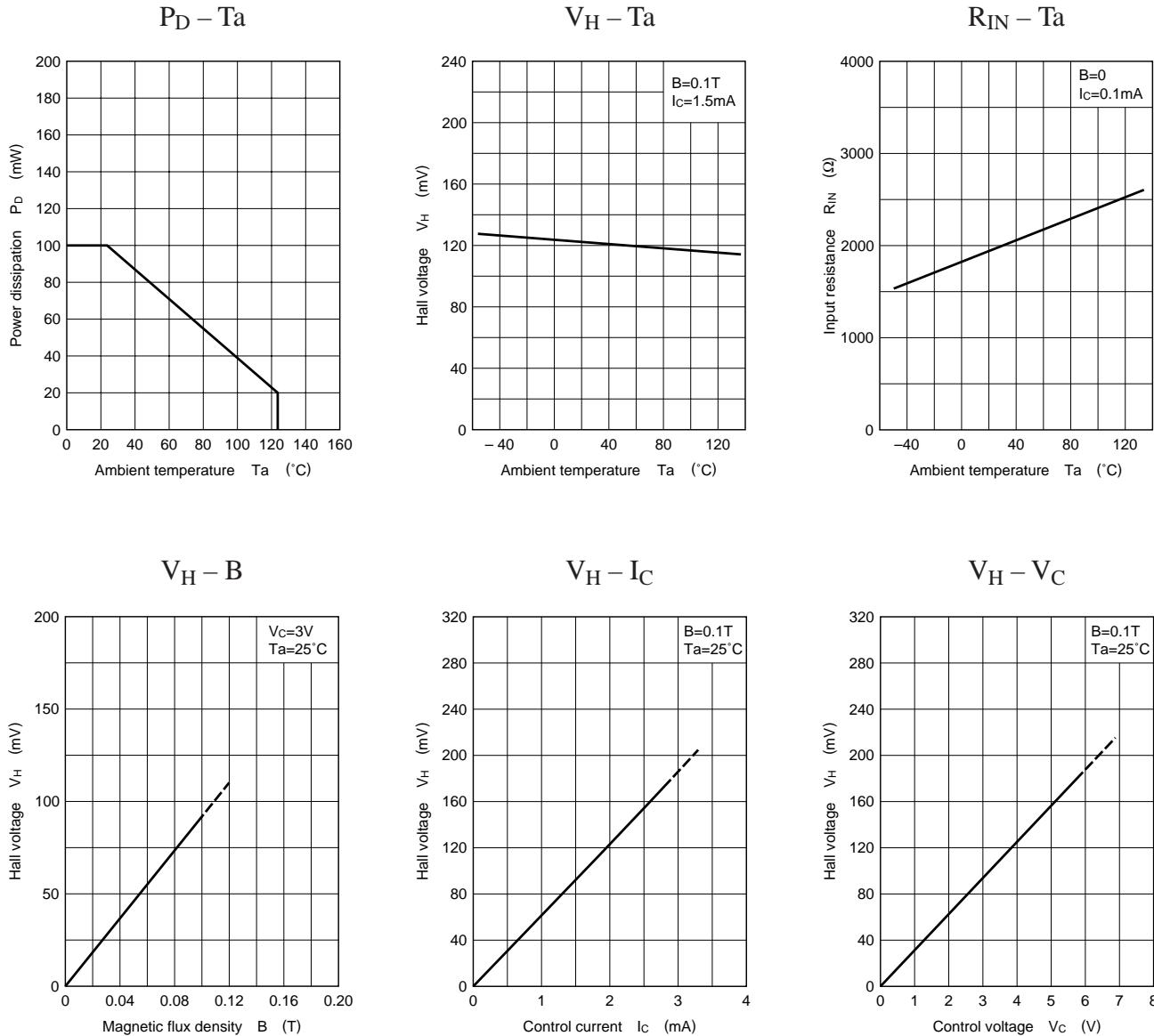
Parameter	Symbol	Condition	min	typ	max	Unit
Hall voltage	V_H^{*1}	$V_C = 3V, B = 0.1T$	70	90	110	mV
Unbalance voltage	V_{HO}^{*2}	$V_C = 3V, B = 0T$			+ 9.5	mV
Input Resistance	R_{IN}	$I_C = 0.1mA, B = 0T$	1.5	2	3	$k\Omega$
Output resistance	R_{OUT}	$I_C = 0.1mA, B = 0T$	5	7	10	$k\Omega$
Temperature coefficient of hall voltage	β	$I_C = 1.5mA, B = 0.1T$			- 0.06	%/°C
Temperature coefficient of input resistance	α	$I_C = 0.1mA, B = 0T$			0.3	%/°C
Linearity of hall voltage	γ^{*3}	$I_C = 1mA, B = 0.05T/0.1T$			2	%

$$*1 V_H = \frac{|V_{H^+}| + |V_{H^-}|}{2}$$

*2 Output pin voltage at no-load ($B = 0$)

*3 The linearity γ of V_H is a percentage of the cumulative sensitivity of $K_{H0.05}$ and $K_{H0.1}$ measured at $B = 0.05T$ and $0.1T$ for the average value.

$$\gamma = \frac{K_{H0.1} - K_{H0.05}}{1/2 (K_{H0.05} + K_{H0.1})} \quad (\text{Percentage of the cumulative sensitivity } K_H = \frac{V_H}{I_C \cdot B})$$



■ Typical Drive Circuit

